

3A, 2MHz, Synchronous Step-Down Converter

Features

- High Efficiency: Up to 95%
- 50 μ A Operating Quiescent Current
- <1 μ A Shutdown Current
- Internal Soft Start Function
- Up to 3A Output Current
- 2.7V to 6.5V Input Voltage Range
- 2MHz Switching Frequency
- No Schottky Diode Required
- 100% Duty Cycle in Dropout Operation
- 1V Reference Allows Low Output Voltages
- Over Temperature Protection
- Hiccup Short-Circuit Protection
- Output Discharge
- RoHS Compliant
- Lead Free and Halogen Free

Applications

- Cellular Telephones
- Personal Information Appliances
- Microprocessors and DSP Core Supplies
- LCD TV and Monitor
- Digital Still and Video Cameras
- Portable Instruments

General Description

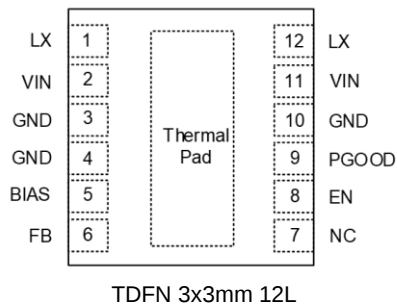
The XPC9082 is a high efficiency monolithic synchronous buck converter using a constant frequency, current mode architecture. Supply current during operation is only 300 μ A and further drops to <1 μ A in shutdown. The 2.7V to 6.5V input voltage range makes the XPC9082 ideally suited for single Li-Ion battery-powered applications. 100% duty cycle provides low dropout operation, extending battery run time in portable systems.

Switching frequency is internally set to 2MHz, allowing the use of small surface mount inductors and capacitors. The internal synchronous switch increases efficiency and eliminates the need for an external Schottky diode. Built-in soft start function prohibits inrush current that could damage the system.

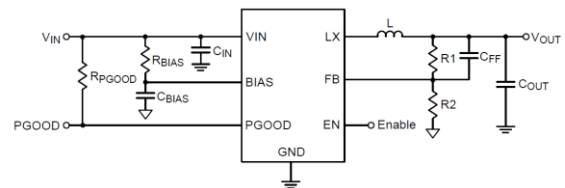
Ordering Information

Part number	Top marking	Output voltage	Temperature range	Package
XPC9082	9082	Adjustable	-40°C to +85°C	TDFN 3x3mm 12L

Pin Configuration



Typical Application Circuit



Absolute Maximum Ratings

VIN to GND	-0.3V to +7V	Thermal Resistance Junction to Case, (θ_{JC})	
EN, FB, PGOOD to GND.	-0.3V to (VIN + 0.3V)	TDFN 3x3-12L.	7°C/W
LX to GND	-0.3V to (VIN + 0.3V)	Operating Temperature Range	-40°C to 85°C
LX to GND	-3V to (VIN + 3V) for <20ns	Maximum Junction Temperature	150°C
Thermal Resistance Junction to Ambient, (θ_{JA})		Storage Temperature Range	-65°C to 165°C
TDFN 3x3-12L.	60°C/W ⁽¹⁾	Reflow Temperature (soldeing,10 sec)	260°C
Continuous Power Dissipation (TA = +25°C)			
TDFN 3x3-12L.	1.667W ⁽¹⁾		

Note:

⁽¹⁾ : Please refer to Minimum Footprint PCB Layout Section.

Electrical Characteristics

(VIN=VEN=3.6V, TA =25°C)

The device is not guaranteed to function outside its operating conditions. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified.

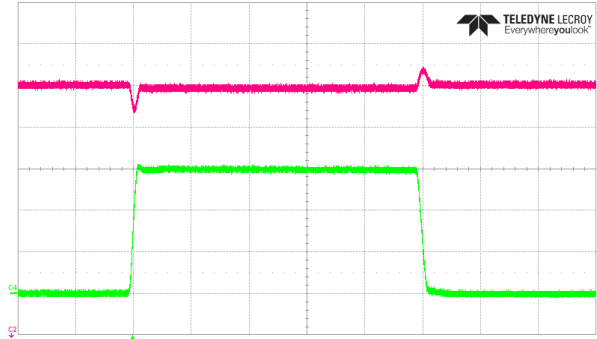
PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNIT
Input Voltage Range	VIN		2.7	---	6.5	V
Quiescent Current	IQ	IOUT=0, VFB=VREF×95%	---	300	---	μA
Shutdown Current	ISHDN	EN=0	---	0.1	1	μA
Feedback Reference Voltage	VREF		0.99	1	1.01	V
PFET RON	RDS(ON),P		---	75	150	mΩ
NFET RON	RDS(ON),N		---	55	80	mΩ
PFET Current Limit	ILIM		3.5	5	---	A
EN rising threshold	VENH		1.5	---	---	V
EN falling threshold	VENL		---	---	0.4	V
Input UVLO threshold	VUVLO		2.25	2.45	2.65	V
UVLO hysteresis	VHYS		---	0.2	---	V
Switching Frequency	FSW		1.7	2	2.3	MHz
Short Circuit Protection Threshold	VSCP		---	0.3	---	V
Min ON Time			---	25	---	ns
Max Duty Cycle			100	---	---	%
Soft Start Time	TSS		---	1	---	ms
Output Discharge Switch On Resistance	RDISCH		---	50	---	Ω
Thermal Shutdown Temperature	TSO		---	150	---	°C
Line regulation		IOUT = 1A, VIN = 2.7V to 6.5V	---	0.05	---	%/V
Load regulation		IOUT = 0.5A to 3A	---	0.2	---	%/A
Power Good Threshold		VFB Rising	---	107	---	%
		VFB Falling	---	93	---	
Enable Input Current			---	0.7	2	uA

Typical Performance Characteristics

($V_{IN}=3.3V$, $V_{OUT}=1.8V$, $C_{IN}=10\mu F \times 2$, $C_{OUT}=10\mu F \times 2$, $L=1\mu H$, $T_A=25^\circ C$)

Load Transient Response

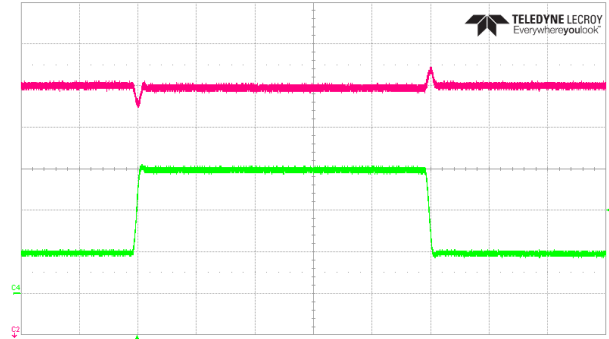
$V_{OUT}=1.8V$, $I_{OUT}=0\sim 3A$



CH2: V_{OUT} 100mV/div; CH4: I_{OUT} 1A/div; Time: 100us/div

Load Transient Response

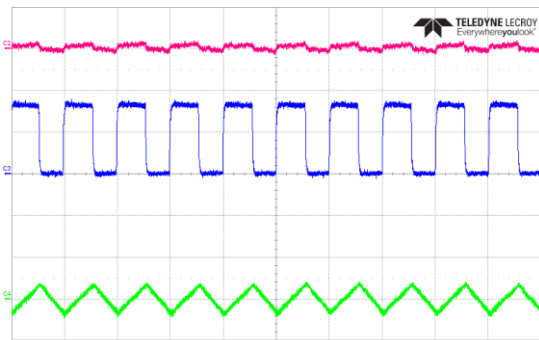
$V_{OUT}=1.8V$, $I_{OUT}=1A\sim 3A$



CH2: V_{OUT} 100mV/div; CH4: I_{OUT} 1A/div; Time: 100us/div

Ripple Voltage

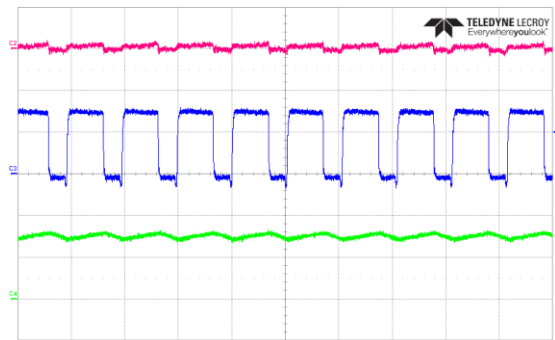
$V_{IN}=3.3V$, $V_{OUT}=1.8V$, Empty Load



CH2: V_{OUT} 50mV/div; CH3: LX 2V/div; CH4: I_{OUT} 0.5A/div; Time: 500ns/div

Ripple Voltage

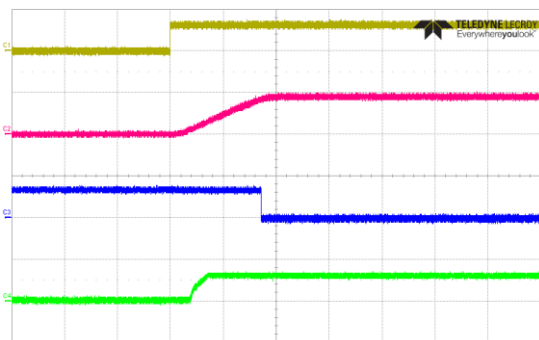
$V_{IN}=3.3V$, $V_{OUT}=1.8V$, $I_{OUT}=3A$



CH2: V_{OUT} 50mV/div; CH3: LX 2V/div; CH4: I_{OUT} 2A/div; Time: 500ns/div

Start-up Through Enable

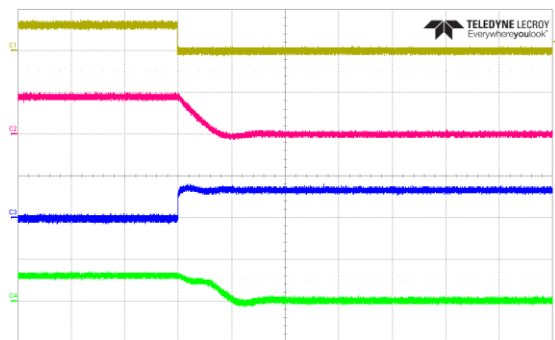
$V_{OUT}=1.8V$, $I_{OUT}=0.5A$



CH1: EN 5V/div; CH2: V_{OUT} 2V/div; CH3: PG 5V/div; CH4: I_{OUT} 1A/div; Time: 500us/div

Shut-down Through Enable

$V_{OUT}=1.8V$, $I_{OUT}=0.5A$

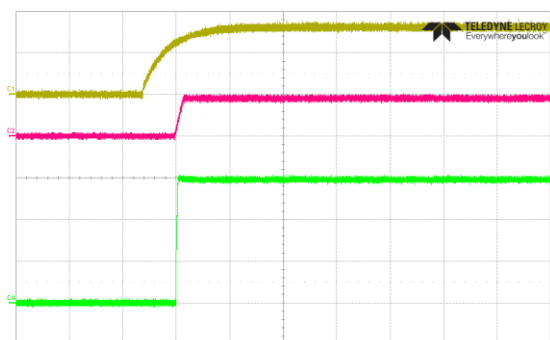


CH1: EN 5V/div; CH2: V_{OUT} 2V/div; CH3: PG 5V/div; CH4: I_{OUT} 1A/div; Time: 20us/div

Typical Performance Characteristics (continued)

Start-up Through V_{IN}

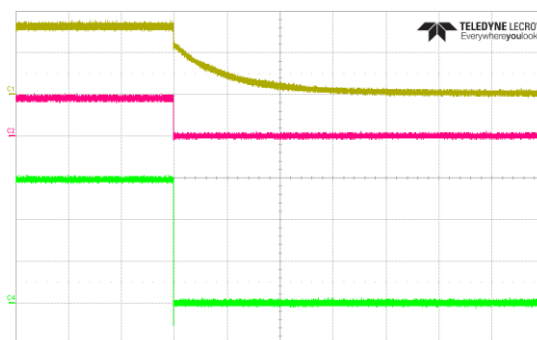
$V_{OUT}=1.8V$, $I_{OUT}=3A$



CH1: V_{IN} 2V/div; CH2: V_{OUT} 2V/div; CH4: I_{OUT} 1A/div; Time: 5ms/div

Shut-down Through V_{IN}

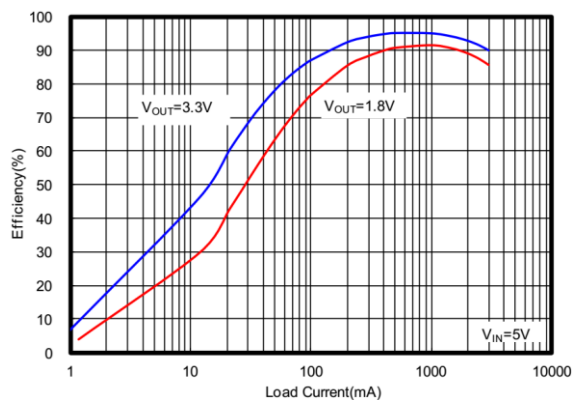
$V_{OUT}=1.8V$, $I_{OUT}=3A$



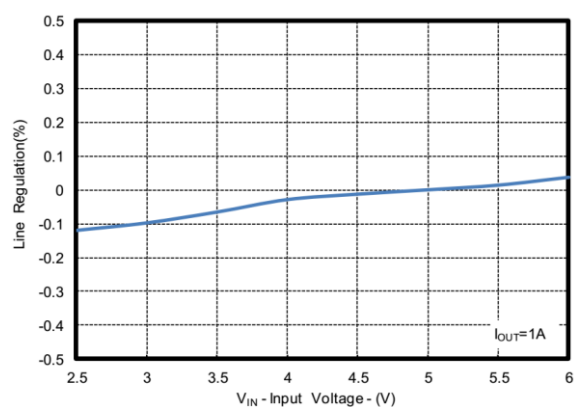
CH1: V_{IN} 2V/div; CH2: V_{OUT} 2V/div; CH4: I_{OUT} 1A/div; Time: 100ms/div

Typical Performance Characteristics (continued)

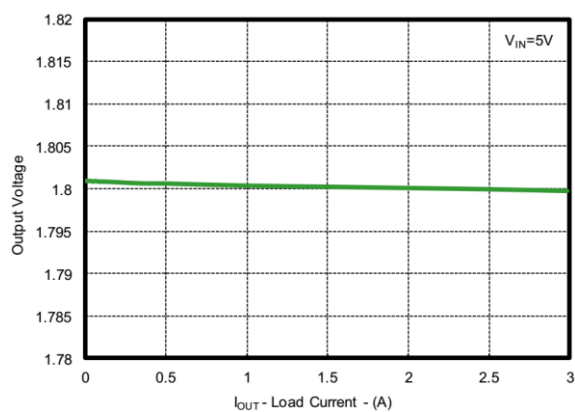
Conversion Efficiency



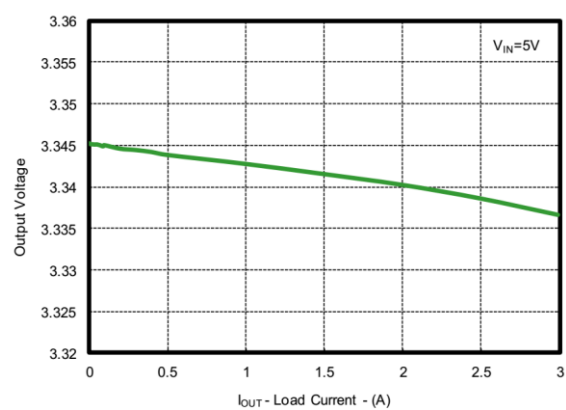
Line Regulation



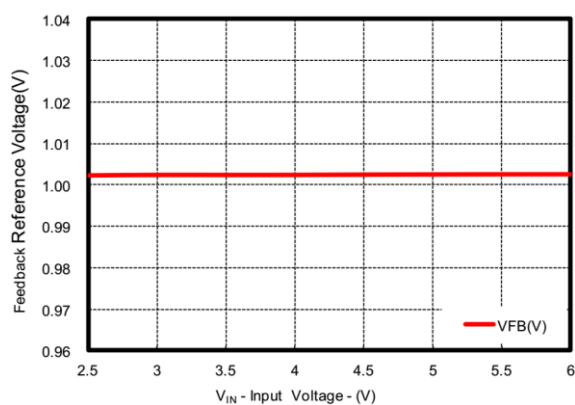
Load Regulation



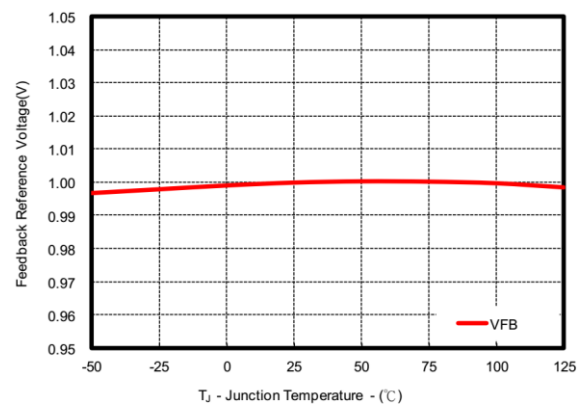
Load Regulation



Reference Voltage vs Input Voltage

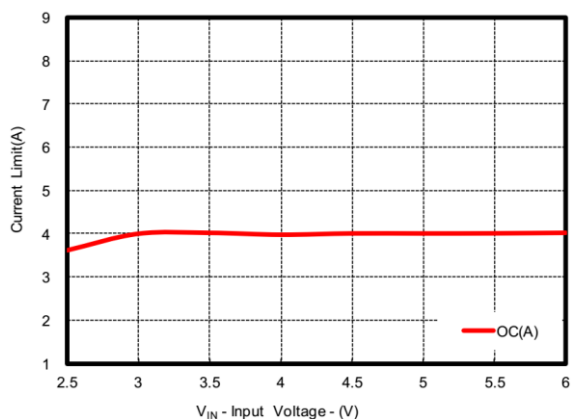


Reference Voltage vs Temperature

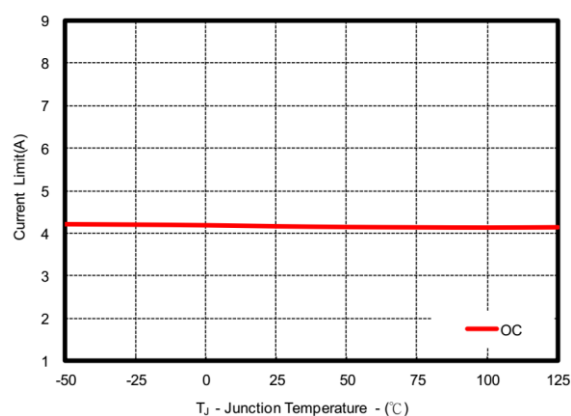


Typical Performance Characteristics (continued)

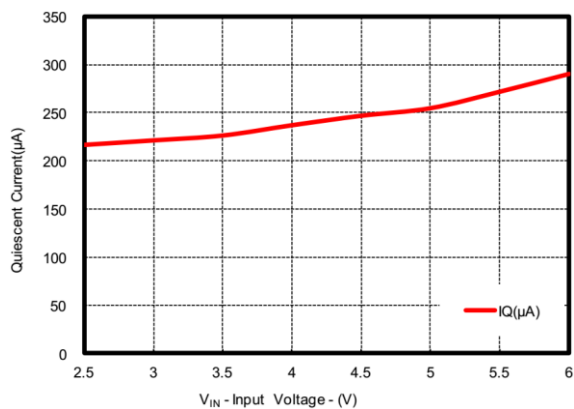
Current Limit vs Input Voltage



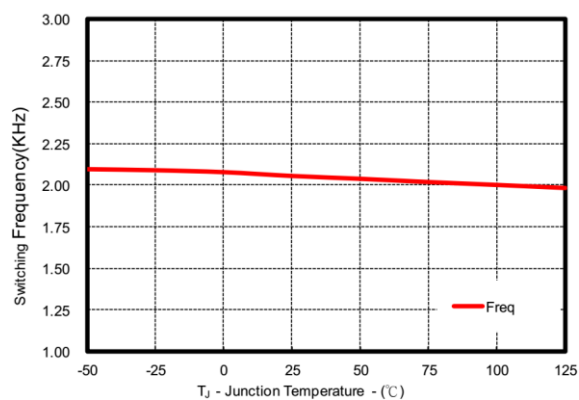
Current Limit vs Temperature



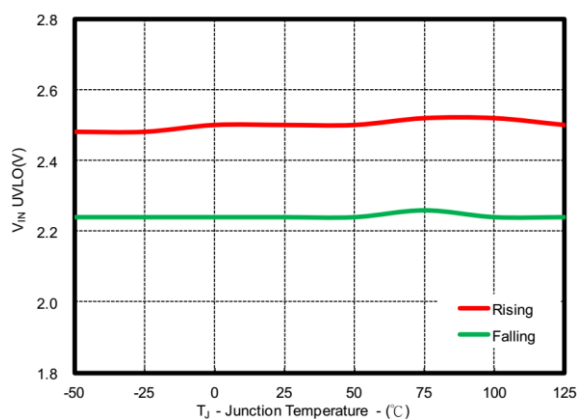
Quiescent Current vs Input Voltage



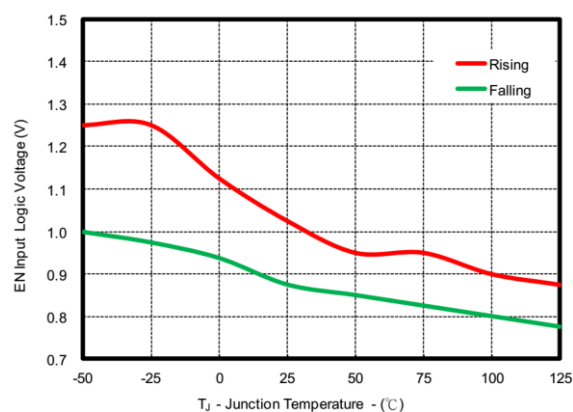
Switching Frequency vs Temperature



UVLO Threshold vs Temperature



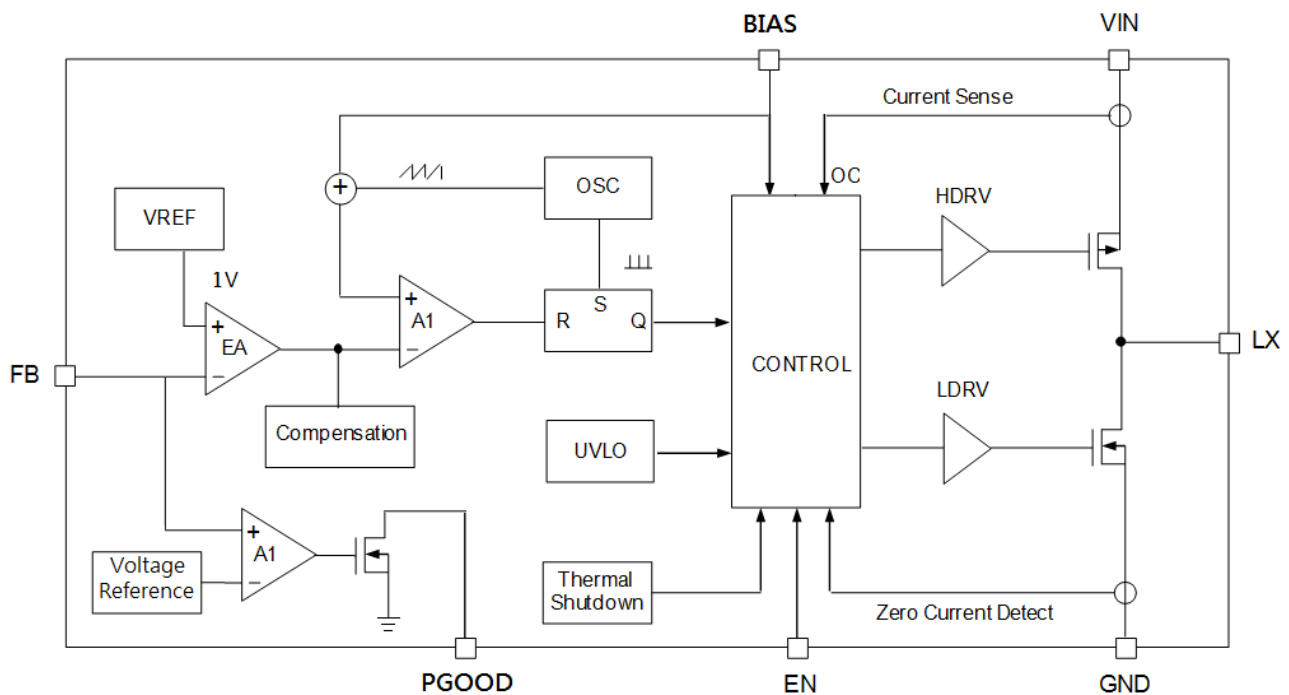
EN Threshold vs Temperature



Pin Descriptions

PIN	NAME	FUNCTION
1, 12	LX	Internal Power MOSFET Switches Output. Connect these pins to the inductor together.
2, 11	VIN	Power Input.
3, 4, 10, EP	GND	Ground Pins.
5	BIAS	Analog Power Input.
6	FB	Feedback Input. This pin is used to set the desired output voltage via an external resistive divider. The feedback reference voltage is 1V typically.
7	NC	No Internal Connection.
8	EN	Enable Control Input. Connect this pin to logic high to enable the device.
9	PGOOD	Power Good Indicator. This pin is an open-drain logic output that is pulled to ground when the output voltage is within 7% of regulation point.

Block Diagram



Function Description

Normal Operation

The XPC9082 implements a constant frequency, current mode step-down architecture. Both high-side and low-side switches are integrated. During normal operation, the internal high-side (PMOS) switch is turned on each cycle when the oscillator sets the SR latch and turned off when the comparator (A1) resets the SR latch. The peak inductor current at which comparator (A1) resets the SR latch, is controlled by the output of error amplifier EA. While the high-side switch is off, the low-side switch is turned on until either the inductor current starts to reverse or the beginning of the next switching cycle.

Dropout Operation

As the input supply voltage decreases to a value approaching the output voltage, the duty cycle increases toward the maximum on-time. Further reduction of the supply voltage forces the high-side switch to remain on for more than one cycle until it reaches 100% duty cycle. The output voltage is dropped from the input supply for the voltage which across the high-side switch.

Over Temperature Protection

The XPC9082 has an integrated over-temperature protection circuit that monitors the device junction temperature, and stop switching if the junction temperature over 150°C. When the junction temperature cools down to 130°C, the device will restart.

Soft-Start

During normal power-up, as the input voltage exceeds UVLO threshold, the soft-start circuitry will slowly ramp up the output voltage. This feature prevents supply inrush current and output voltage overshoots during startup conditions.

Over Current Protection

Cycle-by-cycle peak inductor current limit is used to protect embedded switch from damage. The typical peak current limit is 4.0A. If the current through high-side FET over the current limit threshold, high-side FET is turned off immediately. Hence the maximum output current (the average of inductor current) is also restricted.

Short-circuit Protection

Short-circuit protection will activate once the feedback voltage falls below 0.3V. The operating frequency is folded back to 50% of the normal frequency to prevent inductor current runaway. Also, hiccup-mode is adopted to further reduce power dissipation during short-circuit fault condition. When short circuit status is released, the output voltage will automatically recover and ramp up to the setting voltage.

Power Good Output

The power good output is an open-drain output and requires a pull up resistor. When the output voltage is 7% above or 7% below its set voltage, PGOOD will be pulled high. It is held high until the output voltage returns within the allowed tolerances once more. During soft-start, PGOOD is actively held high and is only allowed to be low when soft-start period is over, and the output voltage reaches 93% of its set voltage.

Under Voltage Lockout Threshold

The IC features input Under Voltage Lockout protection(UVLO). If the input voltage exceeds the UVLO rising threshold voltage (2.45V typ.), the converter will reset and prepare the PWM for operation. If the input voltage falls below the UVLO falling threshold voltage (2.25V typ.) during normal operation, the device will stop switching. The UVLO rising and falling threshold voltage has a hysteresis (0.2V typ.) to prevent noise from causing reset.

Application Information

Inductor Selection

For most applications, the value of the inductor will fall in the range of 1μH to 4.7μH. Its value is chosen based on the desired ripple current. Large value inductors lower ripple current and small value inductors result in higher ripple currents. Higher V_{IN} or V_{OUT} also increase the ripple current ΔI_L :

$$\Delta I_L = \frac{1}{fL} V_{OUT} \left(1 - \frac{V_{OUT}}{V_{IN}} \right)$$

Where f =switching frequency, L =inductance. A reasonable inductor current ripple is usually set as 1/2 to 1/5 of maximum out current.

The DC current rating of the inductor should be at least equal to the maximum load current plus half the ripple current to prevent core saturation. For better efficiency, choose a low DCR inductor.

Capacitor Selection

In continuous mode, the source current of the top MOSFET is a square wave of duty cycle V_{OUT}/V_{IN} . To prevent large voltage transients, a low ESR input capacitor sized for maximum RMS current must be used. The maximum RMS capacitor current is given by:

$$C_{IN} \text{ requires } I_{RMS} \cong I_{O_{MAX}} \frac{\sqrt{V_{OUT}(V_{IN} - V_{OUT})}}{V_{IN}}$$

This formula has a maximum at $V_{IN}=2V_{OUT}$, where $I_{RMS}=I_{OUT}/2$. This simple worst-case condition is commonly used for design because even significant deviations do not offer much relief.

The selection of C_{OUT} is driven by the required effective series resistance (ESR). Typically, once the ESR requirement for C_{OUT} has been met, the RMS current rating generally far exceeds the $I_{RIPPLE(P-P)}$ requirement. The output ripple ΔV_{OUT} is determined by:

$$\Delta V_{OUT} \cong \Delta I_L \left(ESR + \frac{1}{8fC_{OUT}} \right)$$

For a fixed output voltage, the output ripple is highest at maximum input voltage since ΔI_L increases with input voltage.

Nowadays, higher value, lower cost ceramic capacitors are becoming available in smaller case sizes. Their high ripple current, high voltage rating and low ESR make them ideal for switching regulator applications. Because the XPC9082's control loop does not depend on the output capacitor's ESR for stable operation, ceramic capacitors can be used freely to achieve very low output ripple and small circuit size.

When choosing the input and output ceramic capacitors, choose the X5R or X7R dielectric formulations. These dielectrics have the best temperature and voltage characteristics of all the ceramics for given value and size.

Output Voltage Programming

In the adjustable version of XPC9082, the output voltage is set by a resistive divider according to the following formula:

$$V_{OUT} = 1 \cdot \left(1 + \frac{R1}{R2} \right) \text{ Volt.}$$

Parameters Suggestion Table

$V_{OUT}(V)$	$R1(K\Omega)$	$R2(K\Omega)$	$C_{FF}(pF)$	$L(\mu H)$	$C_{OUT}(\mu F)$
3.3	27.6	12	82	2	10 x 2
2.5	18	12	330	1.5	10 x 2
1.8	9.6	12	150	1	10 x 2
1.5	6	12	Open	1	10 x 2
1.2	6	30	180	0.76	10 x 2
1.1	3	30	220	0.68	10 x 2

Efficiency Considerations

Although all dissipative elements in the circuit produce losses, one major source usually account for most of the losses in XPC9082 circuits: I^2R losses. The I^2R loss dominates the efficiency loss at medium to high load currents. To minimize the power consumption

from feedback resistors, a value of between 10k and 1M for both $R1$ and $R2$ is recommended.

The I^2R losses are calculated from the resistances of the internal switches, R_{SW} , and external inductor R_L . In continuous mode, the average output current flowing through inductor L is "chopped" between the main switch and the synchronous switch. Thus, the series resistance looking into the LX pin is a function of both top and bottom MOSFET $R_{DS(ON)}$ and the duty cycle (D) as follows:

$$R_{SW} = (R_{DS(ON)TOP})(D) + (R_{DS(ON)BOTTOM})(1-D)$$

The $R_{DS(ON)}$ for both the top and bottom MOSFETs can be obtained from Electrical Characteristics table. Thus, to obtained I^2R losses, simply add R_{SW} to R_L and multiply the result by the square of the average output current.

Other losses including C_{IN} and C_{OUT} ESR dissipative losses and inductor core losses generally account for less than 2% total additional loss.

Checking Transient Response

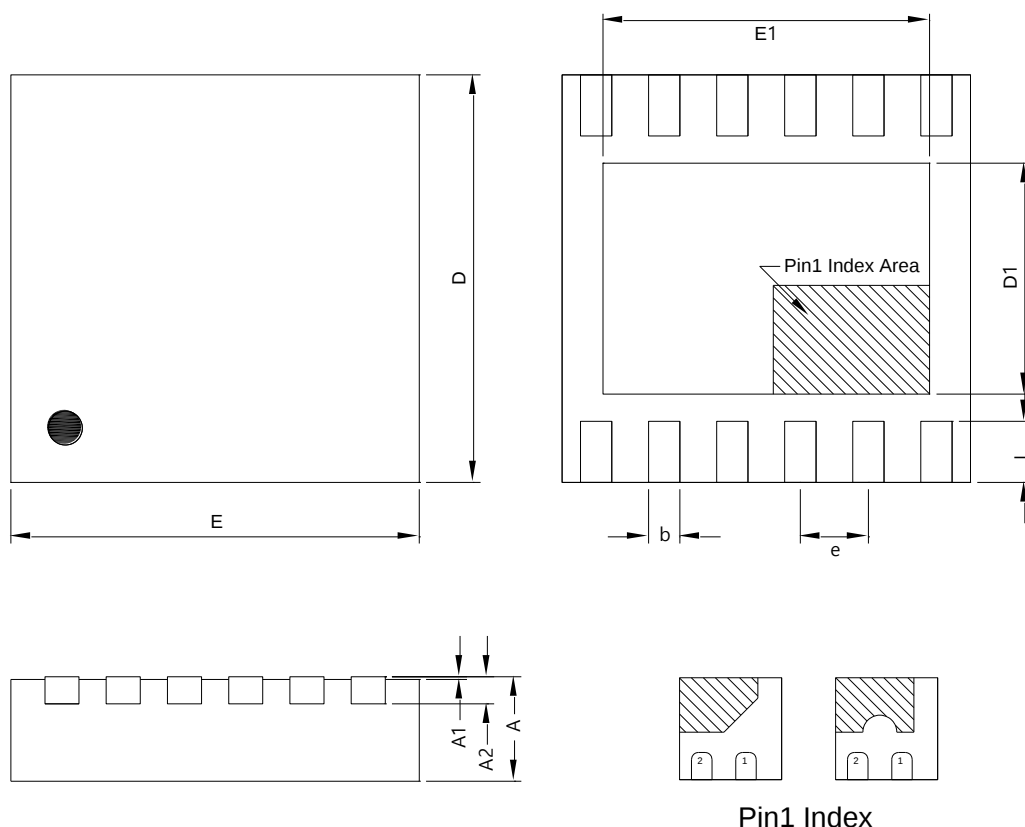
The regulator loop response can be checked by looking at the load transient response. Switching regulators take several cycles to respond to a step-in load current. When a load step occurs, V_{OUT} immediately shifts by an amount equal to $(\Delta I_{LOAD} \cdot ESR)$, where ESR is the effective series resistance of C_{OUT} . ΔI_{LOAD} also begins to charge or discharge C_{OUT} , which generates a feedback error signal. The regulator loop then acts to return V_{OUT} to its steady-state value. During this recovery time V_{OUT} can be monitored for overshoot or ringing that would indicate a stability problem. For large load transient step applications, a 10~22pF ceramic cap in parallel with $R1$ is recommended.

Thermal considerations

In most application the XPC9082 does not dissipate much heat due to its high efficiency. But, in applications where the XPC9082 is running at high ambient temperature with low supply voltage and high duty cycles, such as in dropout, the heat dissipated may exceed the maximum junction temperature of the part. If the junction temperature reaches approximately 150°C, both power switches will be turned off and the LX node will become high impedance.

Assume power dissipation on XPC9082 $P_D=0.1W$, ambient temperature $T_A=70^\circ C$, thermal resistance of junction to ambient $\theta_{JA}=250^\circ C/W$, then temperature junction $T_J = T_A + \theta_{JA} \cdot P_D = 95^\circ C$.

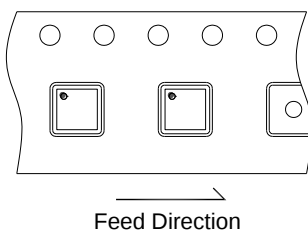
Package Information



TDFN3X3-12 Package

Symbol	DIMENSION IN MM			DIMENSION IN INCH		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.70	0.75	0.80	0.0276	0.0295	0.0315
A1	0.00	---	0.05	0.0000	---	0.0020
A2	0.20 REF			0.0079 REF		
D	2.95	3.00	3.05	0.1161	0.1181	0.1201
E	2.95	3.00	3.05	0.1161	0.1181	0.1201
D1	1.65	1.70	1.75	0.0650	0.0669	0.0689
E1	2.35	2.40	2.45	0.0925	0.0945	0.0965
b	0.18	0.23	0.28	0.0071	0.0091	0.0110
e	0.50 BSC			0.0197 BSC		
L	0.40	0.45	0.50	0.0157	0.0177	0.0197

Taping Specification



PACKAGE	Q'TY/REEL
TDFN3X3-12	3,000ea